



MVD SPD



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Status report of the readout architecture design for the silicon pixel detectors



Outline



- * “Hiccups” in the technology and CAD updates
- * ToPiX version 3 architecture
- * Data transmission
- * Power supplies – news from TWEPP 2009
- * Clock frequency issues



“Hiccups”



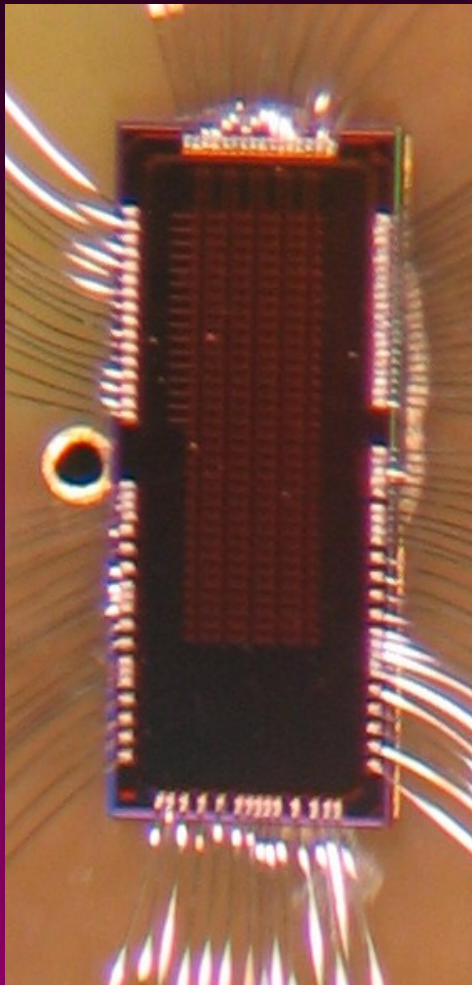
- * Technology : from LM to DM flavour
 - *LM metal layers : 6 thin + 2 thick*
 - *DM metal layers : 3 thin + 2 thick + 3 RF*
 - *more analog-oriented : problems in digital routing*
- * CAD tools : Cadence has changed its database format : from CDB (IC v. 5.1) to OA (IC v. 6.1)
 - *the translation tool has several problems...*
- * Standard cells and pad libraries + design flow :
 - *Old tools from ARM and Manhattan Routing*
 - *New tools from IBM and Cadence*



ToPiX specs



- * Pixel size : $100 \mu\text{m} \times 100 \mu\text{m}$
- * Chip active area : $11.4 \text{ mm} \times 11.6 \text{ mm}$ (116 rows, 110 cols)
- * dE/dx : Time over Threshold, up to 100 fC
- * Analog noise floor : $< 32 \text{ aC}$ ($200 e^-$)
- * System clock frequency : $155 \div 160 \text{ MHz}$
- * Max event and data rates : 12.3 MHz/cm^2 - 815 Mb/s/chip (?)
- * Power consumption : $< 500 \text{ mW/cm}^2$
- * Total Ionizing Dose : $< 100 \text{ kGy}$
- * Equivalent neutron fluence : $< 5 \cdot 10^{14} \text{ 1MeV } n_{\text{EQ}}/\text{cm}^2$



- Full pixel cell (analogue + digital)
- Two folded columns with 128 cells
- Two columns with 32 cells
- $5 \times 2 \text{ mm}^2$ die area
- CMOS $0.13 \mu\text{m}$ LM technology
- Working frequency : 50 MHz
- Dice-based SEU resistant FFs
- Tests :
 - test bench
 - with a sensor and a radiation source
 - TID and SEU



ToPiX v3



New prototype in 0.13 μm under development –
main changes :

- * BEOL option : DM
- * Standard cells library : IBM
- * Clock frequency : 155÷160 MHz
- * SEU protection : triple redundancy
- * More compact analog part



LM vs DM



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	<i>LM</i>	<i>DM</i>
<i>Analogue features</i>		
<i>Routing density</i>		
<i>Power distribution</i>		

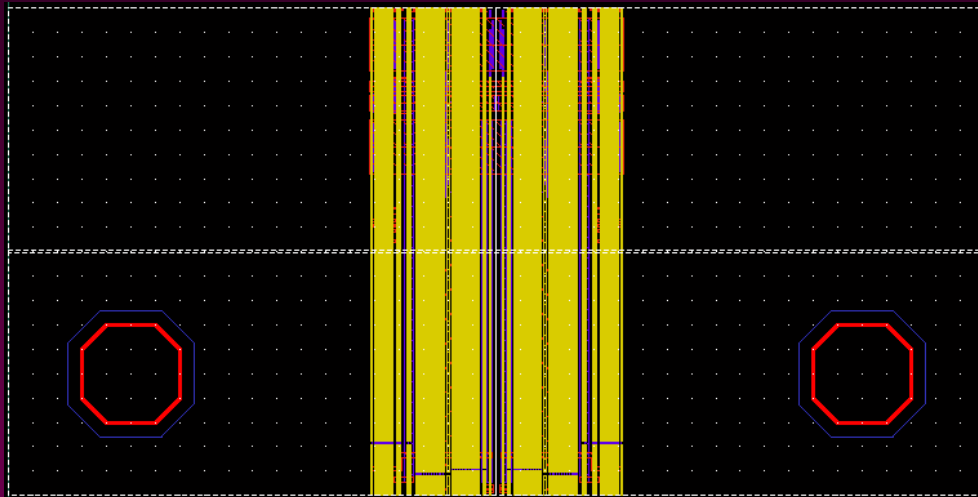


LM vs DM routing



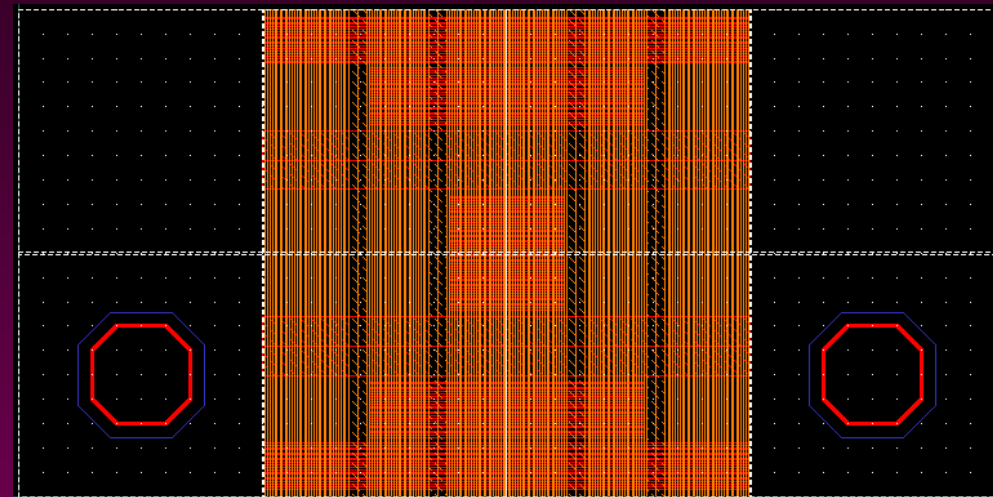
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LM pixel buses



*Bus routed on M4 and M6
Minimum bus pitch $0.4 \mu\text{m}$
Wire resistance : $64 \Omega/\square$
1 readout bus per pixel column*

DM pixel buses



*Bus routed on MG only
Minimum bus pitch $0.8 \mu\text{m}$
Wire resistance : $37 \Omega/\square$
1 readout bus every 2 pixel column*



System aspects



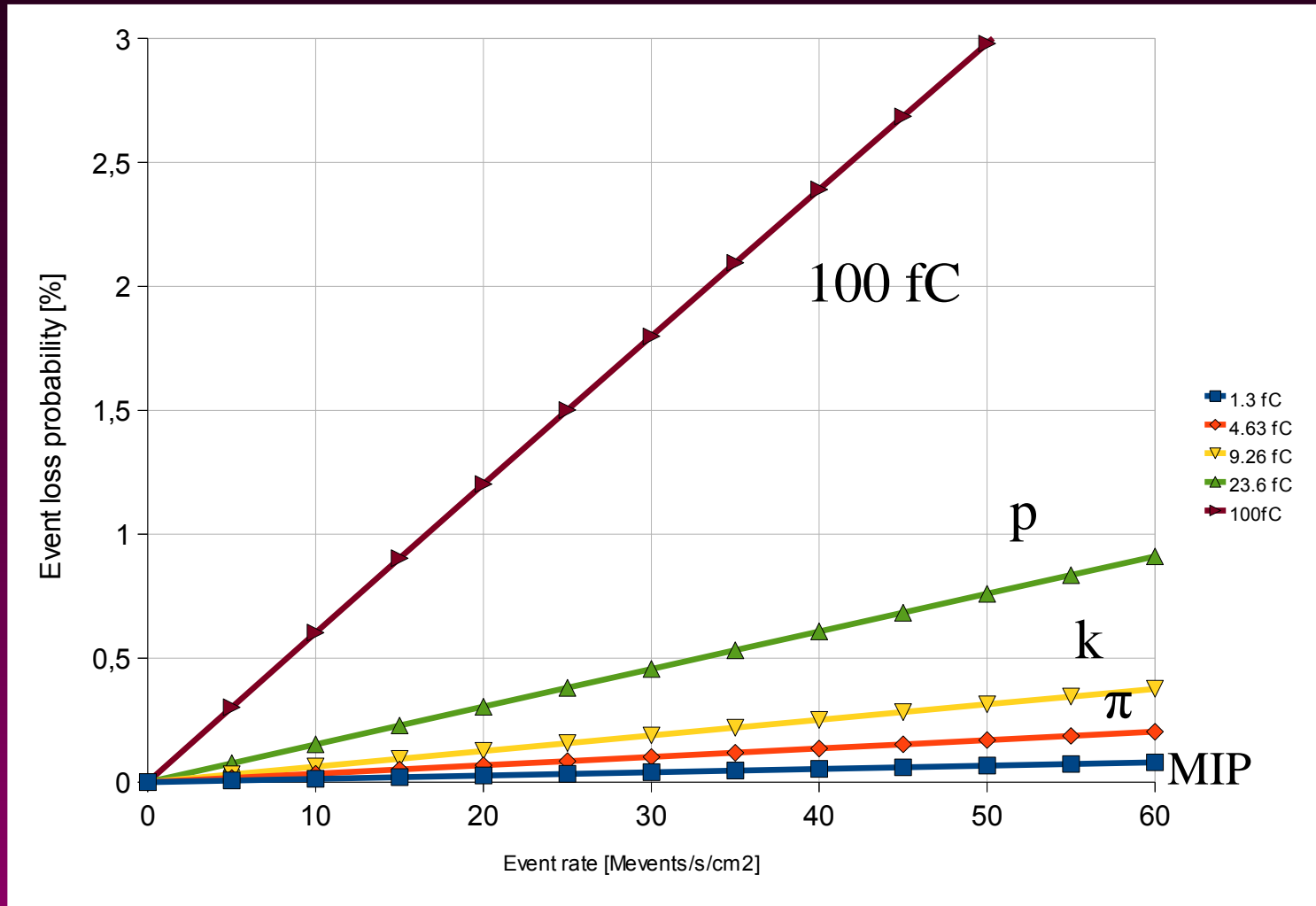
- * Time resolution : 1.8 ns r.m.s. @ 160 MHz
- * Pixel readout time : 8 clock cycles (50 ns)
- * ToT gain : 62.5 ns/fC
- * Pixel dead time @ 1.3 fC : ~90 ns
- * Pixel dead time @ 100 fC : ~6 μ s
- * Chip active area : 1.32 cm²
- * Bits per event : 50

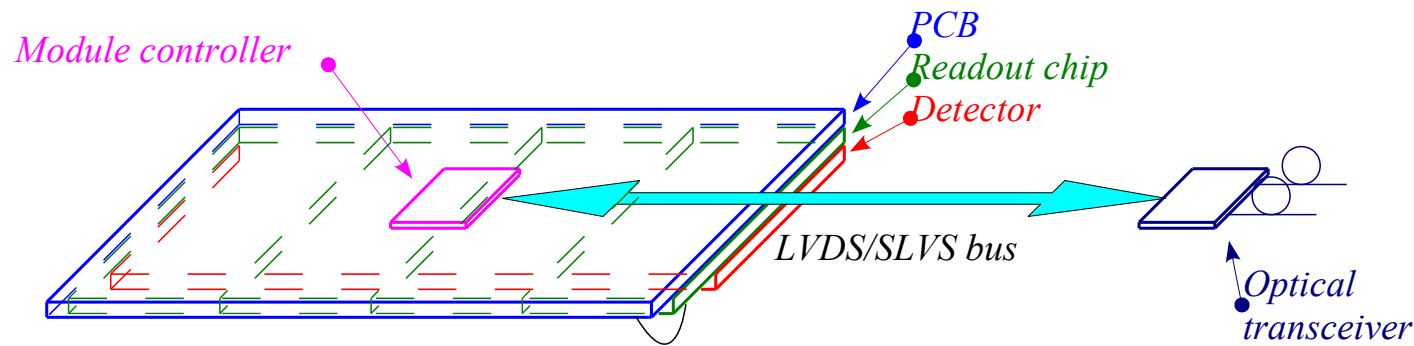


Event loss probability

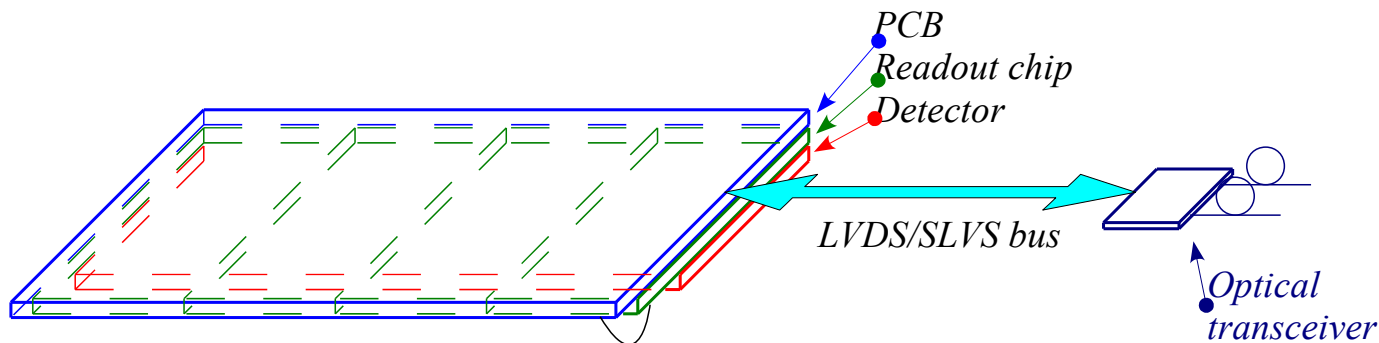


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Option 1



Option 2



Electrical link



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E-link

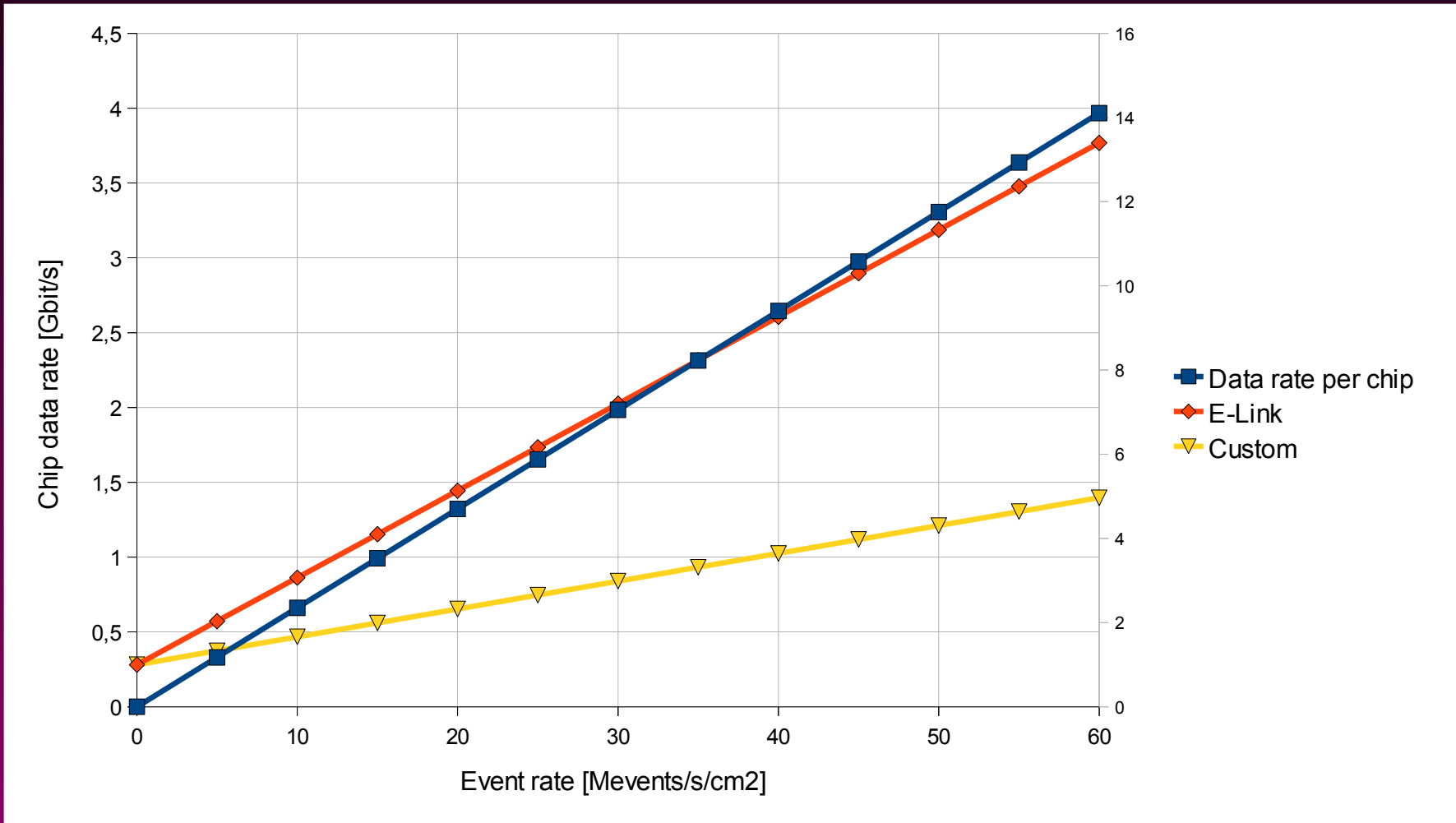
- * Under development for the GBT interface
- * Up to 320 Mbit/s
- * Direct connection to the GBT
- * More cables, less design work

Custom design

- * Target : 1 Gbit/s
- * Common development : PANDA MVD and NA62 GTK
- * More design work, less cables



Data rate vs event rate





Power supply



- * Deep submicron technologies requires lower voltages ($0.35 \mu\text{m} \rightarrow 3.3 \text{ V}$, $0.25 \mu\text{m} \rightarrow 2.5 \text{ V}$, $0.13 \mu\text{m} \rightarrow 1.2 \text{ V}$)
- * Power saving (\sim same current, lower voltage) *but...*
 - power drop on lines and voltage regulator become critical !
- * $500 \text{ mW}/1.2 \text{ V} = 420 \text{ mA} \times 3 \Omega = 1.26 \text{ V} \rightarrow 51\% \text{ efficiency loss for cabling only}$
- * Two solutions are under study in the sLHC community :
 - serial powering
 - DC-DC converters



Serial powering



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- * ATLAS (not official) choice
- * N modules are connected in series with a $N \times V_{DD}$ voltage
- * Shunt regulator to ensure voltage drop (keep current constant)
- * AC connection to the detector and to the DAQ
- * Three configurations :
 - W : on chip shunt regulator and shunt transistor
 - M : on chip shunt transistor, external shunt regulator
 - SPi ext : external shunt regulator and shunt transistor



DC-DC converter



- * CMS official 1st choice
- * Direct voltage conversion via PWM
- * Commonly used in consumer electronics
- * High efficiency
- * Issues for HEP experiments :
 - * noise
 - * inductors in magnetic field



MVD power scheme



- * Just started looking at the issue
- * No manpower for a custom solution
- * Very first feeling : DC-DC looks better
- * PANDA and sLHC timeschedule are similar
 - *we can wait and see who will be the winner...*



MVD pixel requirements



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Basic considerations :

- * in a triggerless environment SPDs generate a lot of data (currently 50 bits/hit : address+time reference+ToT)
 - to fit space and material requirements, we need electrical to optical conversion as close as possible to the detector
- * electronics has to be radiation hard
 - no COTS components can be used
 - looking for solution in the HEP community, especially at development for LHC-sLHC



Clock issue



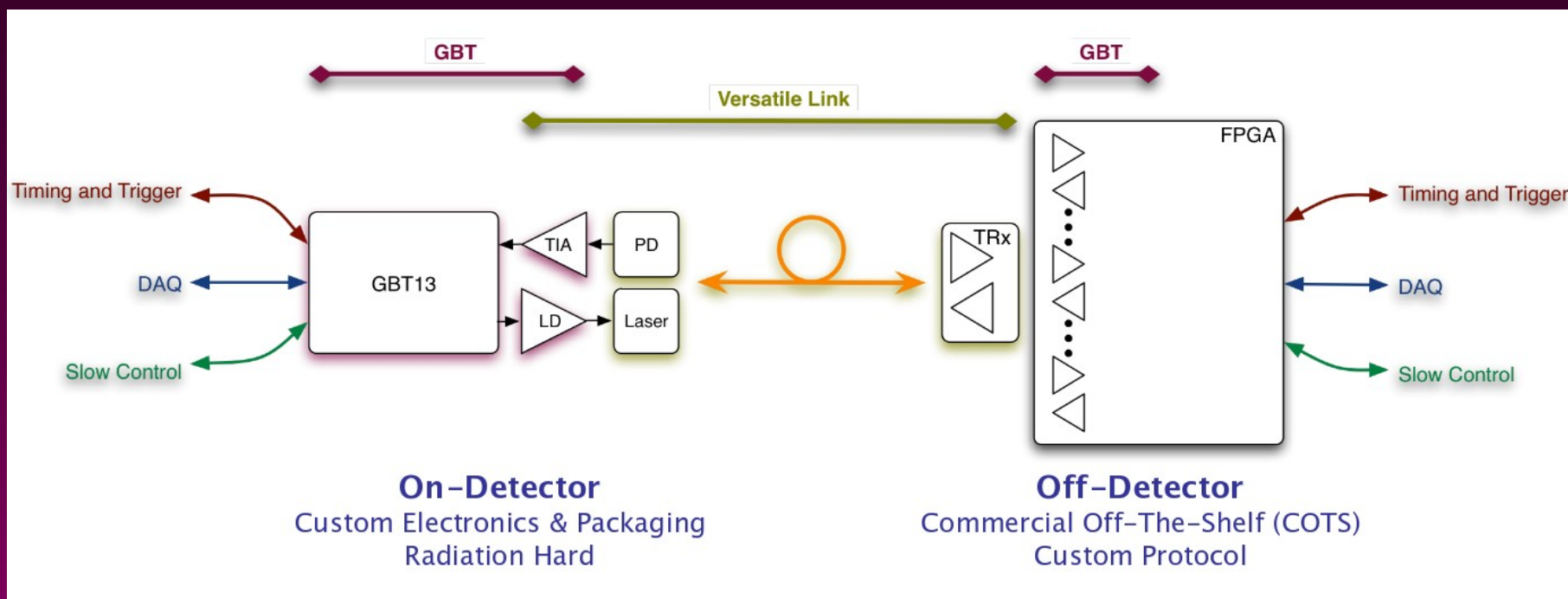
- * ToPiX is (almost) completely synchronous
 - * most performances are defined by the clock (time resolution, dead time, transmission bandwidth, ToT gain)
 - * we do need to freeze the clock frequency (at least $\pm 10\%$)
- * LHC electronics is based on a 40 MHz clock
 - * in principle many ASICs can work at different frequencies but it is not guarantee (ref. QPLL)
 - * for pixel it would be safer to for a $2^N \times 40$ MHz clock
 - * any other PANDA detectors plan to use LHC electronics ?



GBT project



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GBT chipset



Radiation tolerant chipset :

- * GBTIA : Transimpedance optical receiver
- * GBLD : Laser driver
- * GBTx : Data and Timing Transceiver
- * GBT-SCA : Slow control ASIC

Target Applications :

- * Data readout
- * TTC
- * Slow control and monitoring links

Supports :

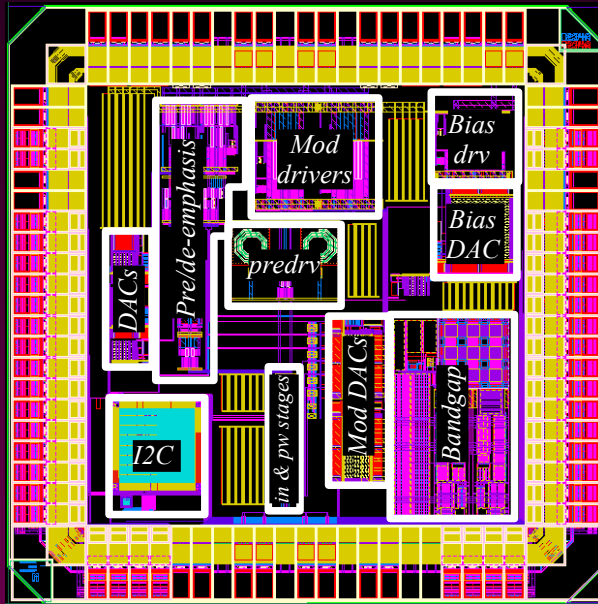
- * Bidirectional data transmission
- * Bandwidth :
 - Line rate : 4.8 Gb/s
 - Effective : 3.36 Gb/s

Radiation Tolerance :

- * Total dose
- * Single Event Upset

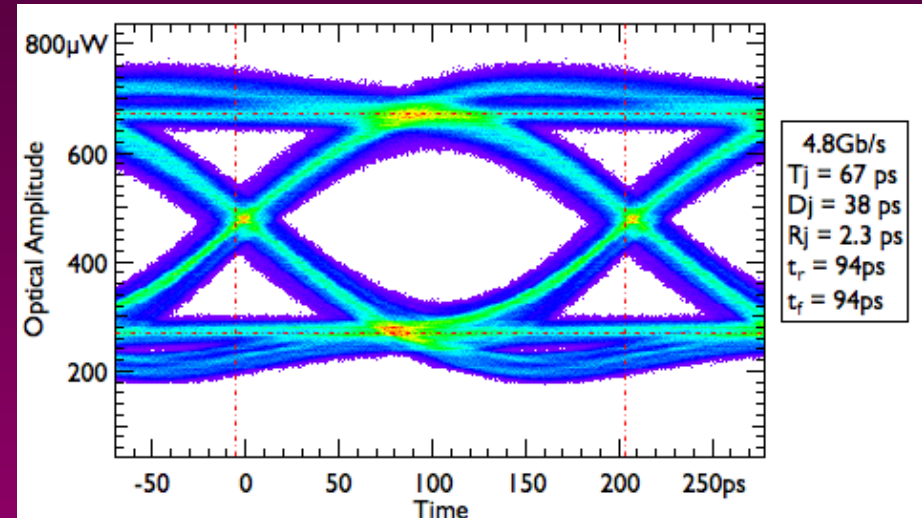


GBLD



- * GBLD : 5 Gb/s laser driver
- * Modulation current : 2÷24 mA
- * Bias current : 2÷43 mA
- * Pre-emphasis/de-emphasis current : 0÷12 mA
- * I2C digital control

Torino contribution to
the GBT project





Conclusions



- * Some “hiccups” in the technology for ToPiX
- * Design of the ToPiX v3 started
 - * *still under the sword of Damocles of the clock frequency...*
- * Ongoing studies on the full architecture :
 - * electrical data transmission
 - * optical conversion and DAQ interface
 - * power supply
- * clock issue